NSN 5961-01-064-9375

A110a0

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-064-9375 **Inclosure Material:** Plastic **Overall Length:** 0.245 inches **Terminal Length:** 0.500 inches **Overall Diameter:** 0.200 inches **Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-98 **Mounting Method: Terminal Terminal Circle Diameter:** 0.100 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 9.0 breakover voltage, dc and 9.0 reverse voltage, peak **Current Rating Per Characteristic:** 200.00 milliamperes source cutoff current preset **Maximum Operating Tempurature Per Measurement Point:** 250.0 degrees celsius ambient air **Special Features:** Junction pattern arrangement: pnpn **Terminal Type And Quantity:** 3 uninsulated wire lead **Specification Data:** 80131-release5472 professional/industrial association specification Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: